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C. A. Fiorilla

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Kishor P. Gadkaree

Joseph F. Mach

Serial No.:

09/991,401

Filing Date:

November 20, 2001

Title:

COMPRESSION-MOLDED SILICON

CARBIDE STRUCTURES

BOX NON-FEE AMENDMENT Assistant Commissioner for Patents Washington, DC 20231

Sir:

CERTIFICATE OF MAILING (37 CFR 1.8a)

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope Addressed to: Assistant Commissioner for Patents, Washington, DC 20231, on Januagy 6, 2003

Anca C. Gheorghiu

Group Art Unit:

Examiner:

RESPONSE TO THE EXAMINER'S OFFICE ACTION

In reply to the Office Action dated 10/04/2002, designated as Paper No. 6 in the above-captioned application, please enter the following amendments and remarks as follows:

In the Claims

Please cancel claims 9, 17-36 without prejudice.

Please replace claims 1 and 10 with the following amended claims:

1. (Amended) A process for forming a silicon carbide structure, comprising:

forming a mixture of a silicon precursor powder, a cross-linking thermoset resin and a silicon-containing filler selected from powder of the group consisting of silicon carbide, silicon nitride and silicate materials;

compression molding the mixture to form a rigid structure;

carbonizing the rigid structure in an inert atmosphere at a temperature in a range from about 700 to 1000°C to convert the cross-linking thermoset resin to carbon; and

heating the rigid structure in an inert atmosphere to a temperature in a range from about 1400 to 1800°C to allow the carbon to react with silicon in the rigid structure to form silicon carbide.

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10. (Amended) The process of claim 1, wherein the silicon-containing filler is silicon carbide.